



TF256TH

N-Channel JFET

20V, 140 to 450 μ A, 1.7mS, VTFP

ON Semiconductor®

<http://onsemi.com>

Features

- High gain : $G_V=2.7\text{dB}$ typ ($V_{CC}=2\text{V}$, $R_L=2.2\text{k}\Omega$, $C_{in}=5\text{pF}$, $V_{IN}=10\text{mV}$, $f=1\text{kHz}$)
- Ultrasmall package facilitates miniaturization in end products
- Best suited for use in electret condenser microphone for audio equipments and telephones
- Excellent transient characteristics
- Adoption of FBET process
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

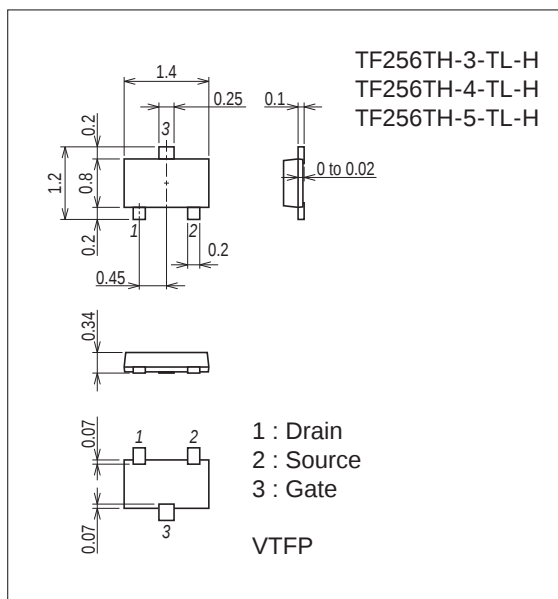
Parameter	Symbol	Conditions	Ratings	Unit
Gate-to-Drain Voltage	V_{GDO}		-20	V
Gate Current	I_G		10	mA
Drain Current	I_D		1	mA
Allowable Power Dissipation	P_D		100	mW
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

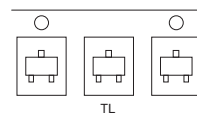
7031A-001



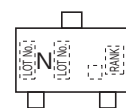
Product & Package Information

- Package : VTFP
- JEITA, JEDEC : SC-106A
- Minimum Packing Quantity : 8,000 pcs./reel

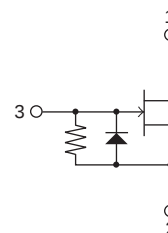
Packing Type: TL



Marking



Electrical Connection



TF256TH

Electrical Characteristics at Ta=25°C

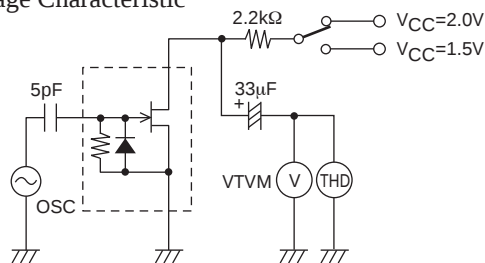
Parameter	Symbol	Conditions	Ratings				Unit
			Rank	min	typ	max	
Gate-to-Drain Breakdown Voltage	V(BR)GDO	I _G =−100μA		−20			V
Cutoff Voltage	V _{GS(off)}	V _{DS} =2V, I _D =1μA		−0.1	−0.35	−1.0	V
Drain Current	I _{DSS} *	V _{DS} =2V, V _{GS} =0V	3	100		180	μA
			4	140		280	
			5	240		450	
Forward Transfer Admittance	y _{fs}	V _{DS} =2V, V _{GS} =0V, f=1kHz		0.75	1.7		mS
Input Capacitance	C _{iss}	V _{DS} =2V, V _{GS} =0V, f=1MHz			3.1		pF
Reverse Transfer Capacitance	C _{rss}				1.0		pF
[T _a =25°C, V _{CC} =2.0V, R _L =2.2kΩ, C _{in} =5pF, See specified Test Circuit.]							
Voltage Gain	G _V	V _{IN} =10mV, f=1kHz	3		1.0		dB
			4		2.0		
			5		3.0		
Reduced Voltage Characteristic	ΔG _{VV}	V _{IN} =10mV, f=1kHz, V _{CC} =2.0V → 1.5V	3		−0.5	−1.0	dB
			4		−0.6	−1.3	
			5		−0.9	−2.0	
Frequency Characteristic	ΔG _{Vf}	f=1kHz to 110Hz				−1.0	dB
Total Harmonic Distortion	THD	V _{IN} =30mV, f=1kHz	3		1.4		%
			4		0.9		
			5		0.35		
Output Noise Voltage	V _{NO}	V _{IN} =0V, A curve			−105	−100	dB

* : The TF256TH is classified by I_{DSS} as follows : (unit : μA)

Rank	3	4	5
I_{DSS}	100 to 180	140 to 280	240 to 450

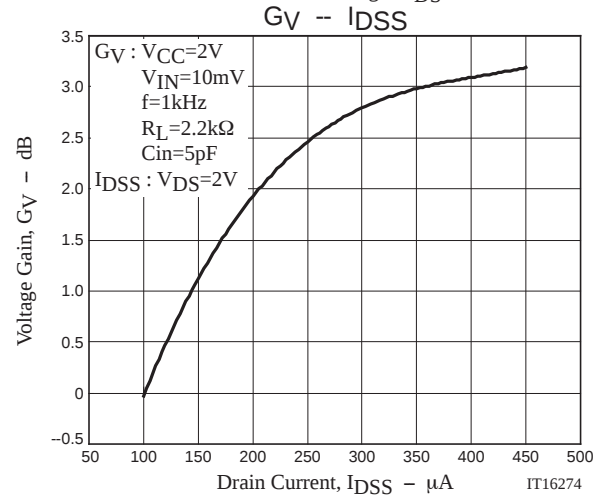
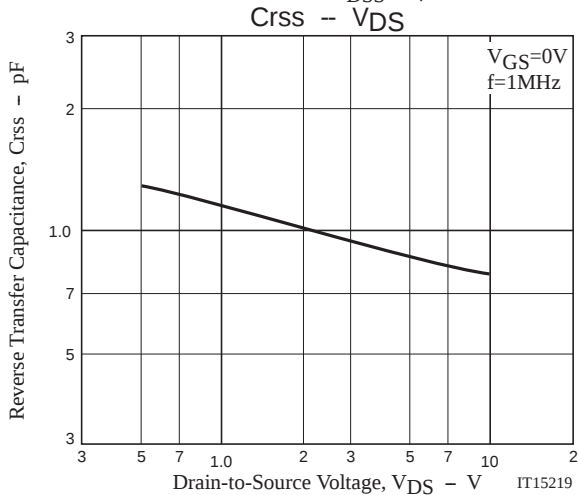
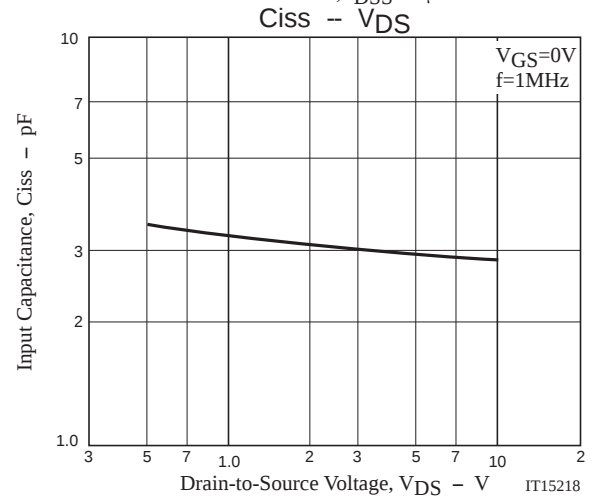
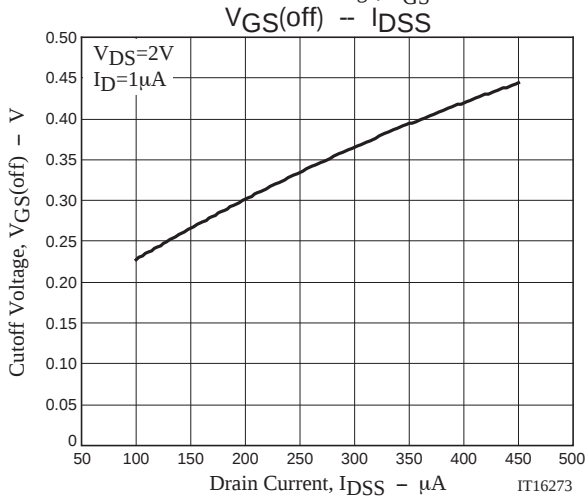
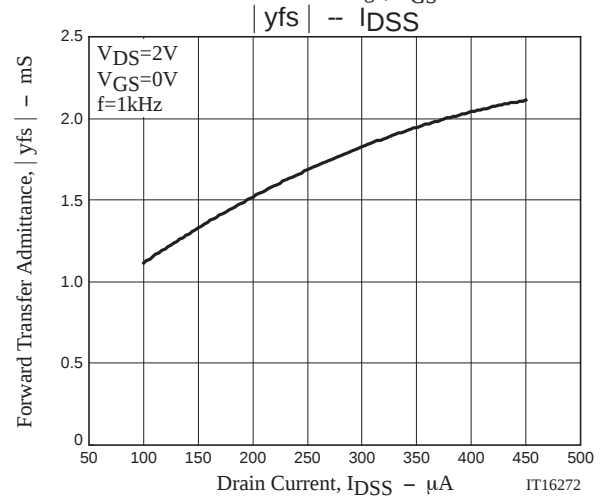
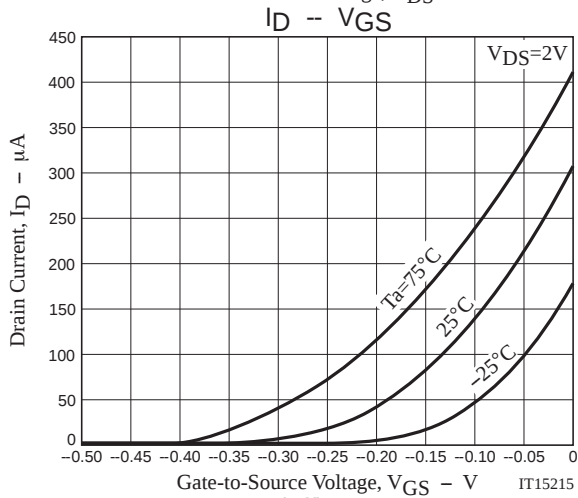
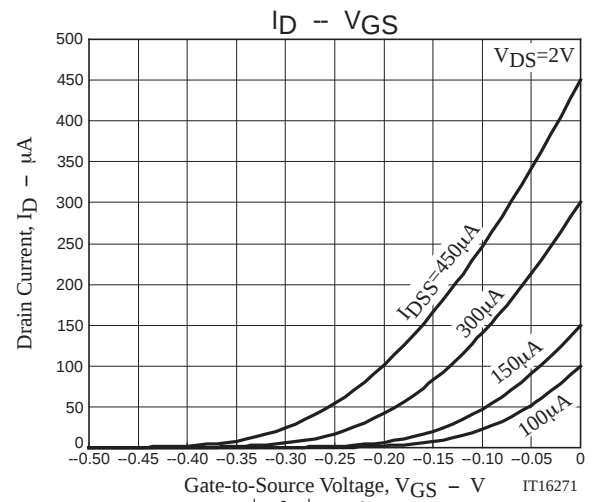
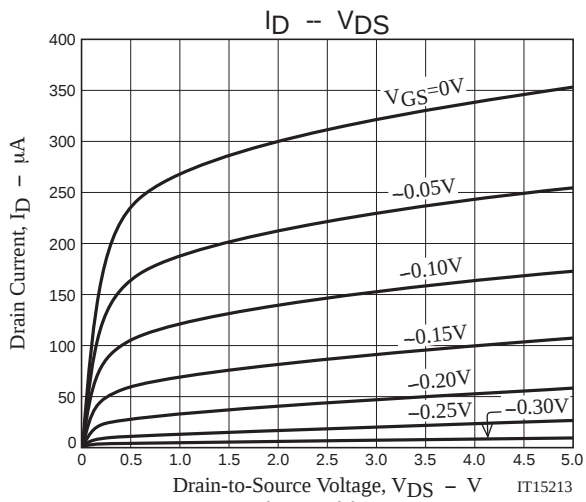
Test Circuit

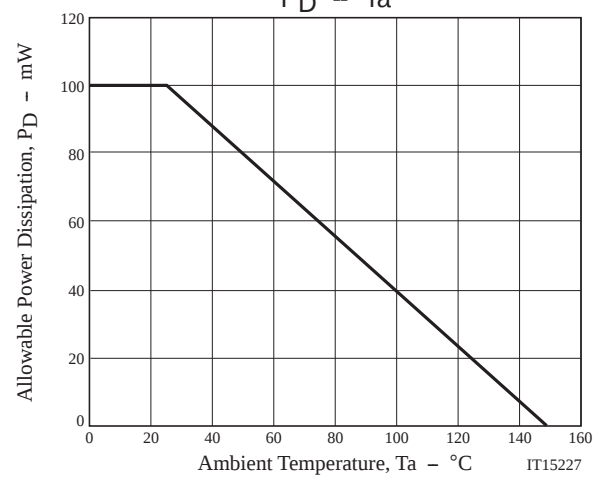
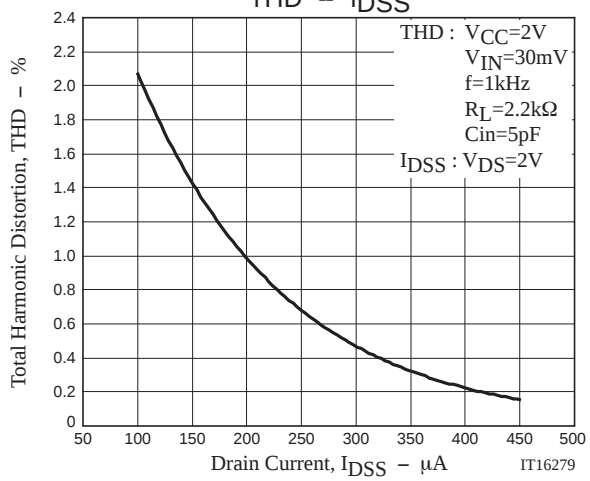
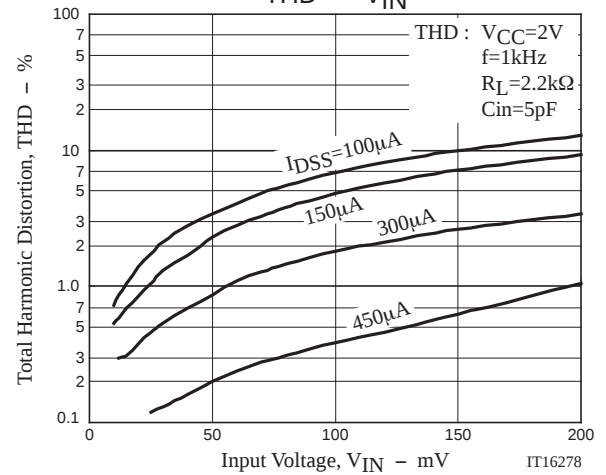
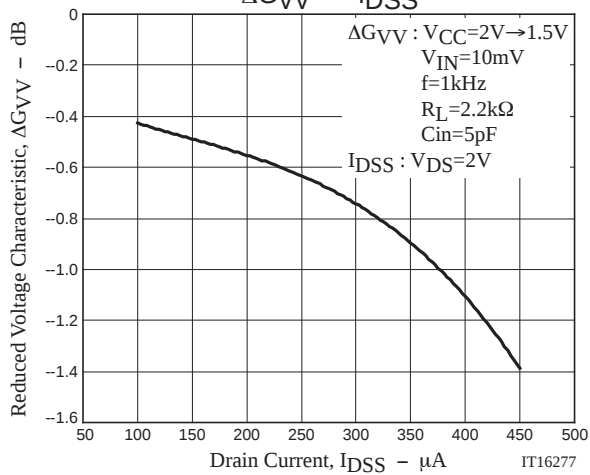
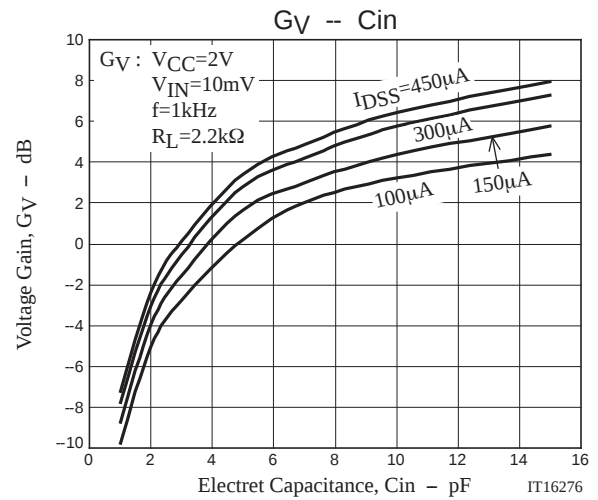
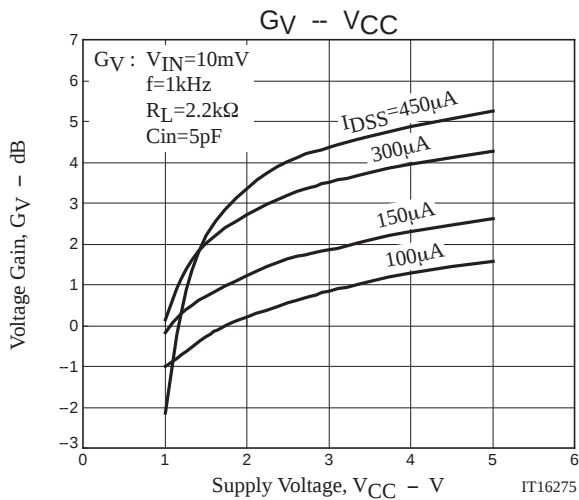
Voltage gain
Frequency Characteristic
Distortion
Reduced Voltage Characteristic



Ordering Information

Device	Package	Shipping	memo
TF256TH-3-TL-H	VTFP	8,000pcs./reel	Pb Free and Halogen Free
TF256TH-4-TL-H	VTFP	8,000pcs./reel	
TF256TH-5-TL-H	VTFP	8,000pcs./reel	





Taping Specification

TF256TH-3-TL-H, TF256TH-4-TL-H, TF256TH-5-TL-H

1. Packing Format

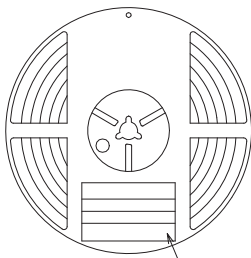
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
VTFP	VSFP	8,000	40,000	240,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit:mm)

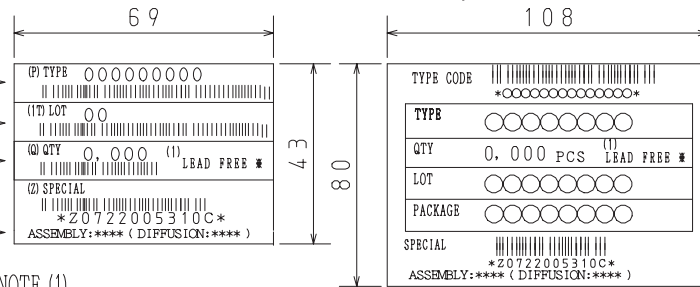
Outer box label

It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Reel label

Type No.
LOT No.
Quantity
Origin

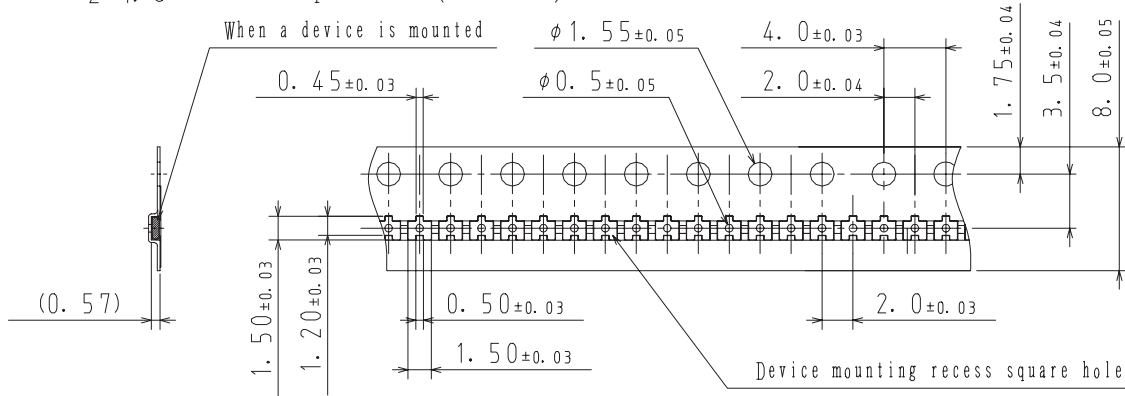
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

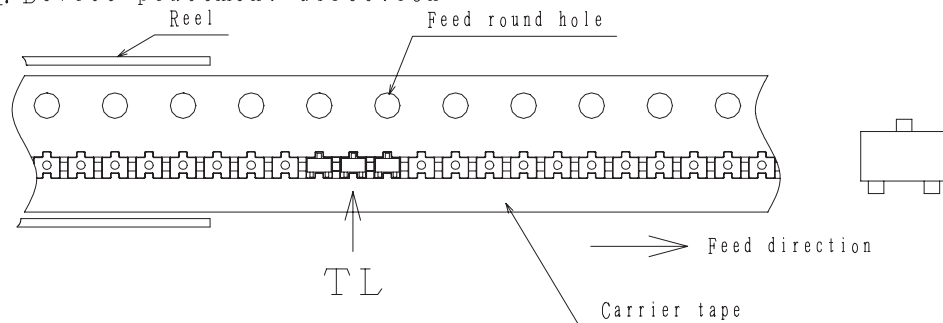
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

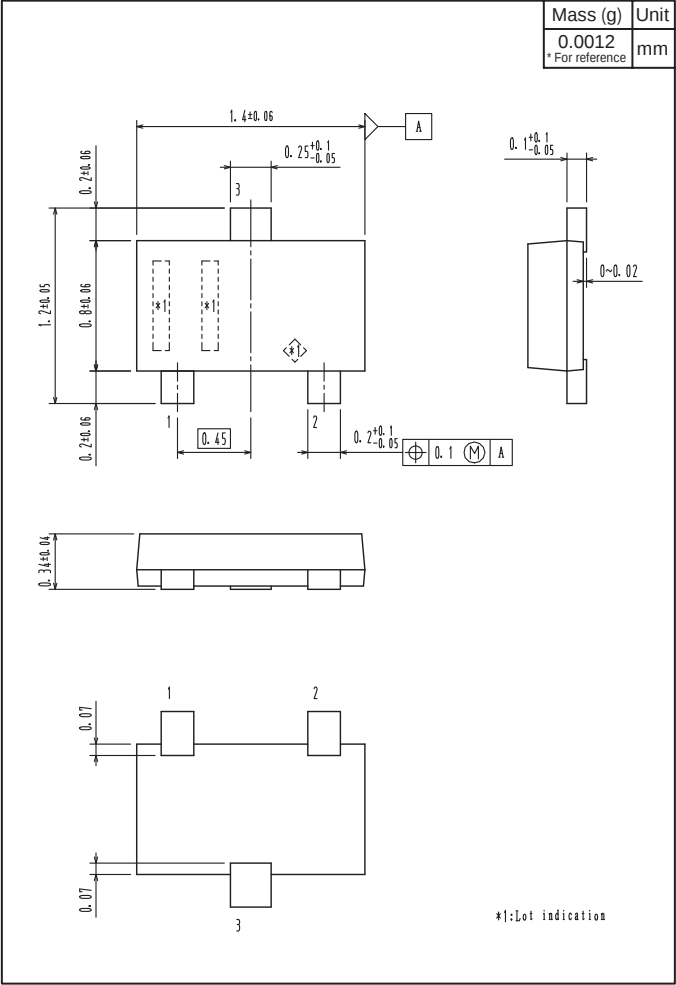


Those with oen electrode terminal on the feed hole side.....TL

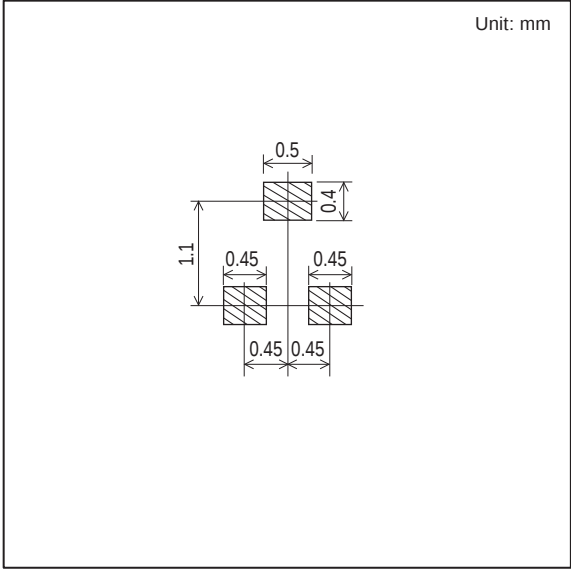
TF256TH

Outline Drawing

TF256TH-3-TL-H, TF256TH-4-TL-H, TF256TH-5-TL-H



Land Pattern Example



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